

<b>PATENT ASSIGNMENT COVER SHEET</b>
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Electronic Version v1.1  
 Stylesheet Version v1.2

EPAS ID: PAT5110088

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
EINAT OPHIR ARAD	08/20/2018
SHARON LEVIN	08/20/2018
ALLON PARAG	08/20/2018
ERAN LIPP	08/20/2018
YOSEF AVRAHAMOV	08/20/2018
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	TOWER SEMICONDUCTOR LTD.
<b>Street Address:</b>	RAMAT GABRIEL INDUSTRIAL AREA
<b>Internal Address:</b>	P.O. BOX 619
<b>City:</b>	MIGDAL HAEMEK
<b>State/Country:</b>	ISRAEL
<b>Postal Code:</b>	23105
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
<b>Application Number:</b>	16112466
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(408)645-6548
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
<b>Phone:</b>	408-718-1799
<b>Email:</b>	credick@beverlaw.com
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<b>Address Line 1:</b>	39500 STEVENSON PLACE
<b>Address Line 2:</b>	SUITE 209
<b>Address Line 4:</b>	FREMONT, CALIFORNIA 94539
<b>ATTORNEY DOCKET NUMBER:</b>	TSL-233
<b>NAME OF SUBMITTER:</b>	PATRICK T. BEVER
<b>SIGNATURE:</b>	/Patrick T. Bever/
<b>DATE SIGNED:</b>	08/24/2018

**Total Attachments: 1**

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ASSIGNMENT

For good and valuable consideration, receipt of which is hereby acknowledged, we

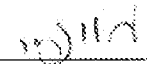
Einat Ophir Arad of Ramat Gabriel Industrial Area P.O. Box 619 Migdal Haemek Israel 23105  
Sharon Levin of Ramat Gabriel Industrial Area P.O. Box 619 Migdal Haemek Israel 23105  
Allon Parag of Ramat Gabriel Industrial Area P.O. Box 619 Migdal Haemek Israel 23105  
Eran Lipp of Ramat Gabriel Industrial Area P.O. Box 619 Migdal Haemek Israel 23105  
Yosef Avrahamov of Ramat Gabriel Industrial Area P.O. Box 619 Migdal Haemek Israel 23105

hereby sell, assign and transfer to **Tower Semiconductor Ltd.**, an Israeli corporation, having a place of business at Ramat Gabriel Industrial Area, P.O. Box 619, Migdal Haemek, Israel 23105, its successors and assigns, the entire right, title and interest throughout the world in our invention in

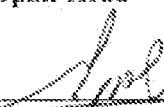
“HIGH-VOLTAGE SILICON-ON-INSULATOR DEVICE WITH DIODE CONNECTION TO HANDLE LAYER”

for which a United States patent application was filed, or will be filed on or about the date of the this Assignment, and all patent applications and patents of every country for said invention, including divisions, reissues, continuations and extensions thereof, and all rights of priority resulting from the filing of said applications; we authorize the above-named joint assignees to apply for patents of foreign countries for said invention, and to claim all rights of priority without further authorization from us; we agree to execute all papers useful in connection with said United States and foreign applications, and generally to do everything possible to aid said joint assignees, their successors, assigns and nominees, at their request and expense, in obtaining and enforcing patents for said invention in all countries; and we request the Commissioner of Patents and Trademarks to issue all patents granted for said invention to the above-named joint assignees, its successors and assigns.

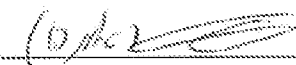
Executed this 20 day of Aug, 2018.

  
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Einat Ophir Arad

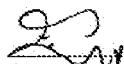
Executed this 20 day of Aug, 2018.

  
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Sharon Levin

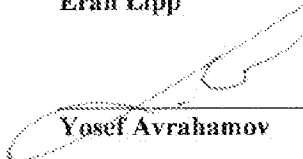
Executed this 20 day of Aug, 2018.

  
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Allon Parag

Executed this 20 day of Aug, 2018.

  
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Eran Lipp

Executed this 20 day of Aug, 2018.

  
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Yosef Avrahamov